







OP07, OP07C, OP07D SLOS099H - SEPTEMBER 1983 - REVISED MARCH 2023

OP07x Precision Operational Amplifiers

1 Features

- Low noise
- No external components required
- Replace chopper amplifiers at a lower cost
- Wide input-voltage range: 0 V to \pm 14 V (typ, \pm 15-V supply)
- Wide supply-voltage range: ±3 V to ±18 V

2 Applications

- Analog input module
- Battery test
- Lab and field instrumentation
- Temperature transmitter
- Merchant network & server PSU

3 Description

The OP07C and OP07D (OP07x) devices offer low offset and long-term stability by means of a lownoise, chopperless, bipolar-input-transistor amplifier circuit. For most applications, external components are not required for offset nulling and frequency compensation. The true differential input, with a wide input-voltage range and outstanding commonmode rejection, provides maximum flexibility and performance in high-noise environments and in noninverting applications. Low bias currents and extremely high input impedances are maintained over the entire temperature range.

For improved performance and wider temperature range, see the next generation OPA207 with low power, and OPA202 with heavy capacitive load drive capability.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
	D (SOIC, 8)	4.90 mm × 3.91 mm
OP07C, OP07D	P (PDIP, 8)	9.81 mm × 6.35 mm
	PS (SO, 8)	6.20 mm × 5.30 mm

For all available packages and the OP07, see the orderable addendum at the end of the data sheet.

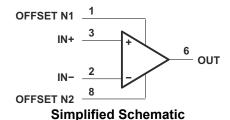




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	feature bullet1
117	3
 Changed supply voltage abbreviation from VCC+ ar 	ad VCC to V in Absolute Maximum Patings and
	4
Changed note 5 in Absolute Maximum Ratings to ince	
	4
•	el and Charged-device model from 1000 V to ±1000 V 4 4
	5
 Changed parameter name from supply-voltage sens 	sitivity to power supply rejection ratio in Electrical
	to be a first of the second of
	to Input voltage noise density in <i>Electrical Characteristics</i>
	5
	Hz to pA/ $√$ Hz in <i>Electrical Characteristics</i> 5
	tial voltage gain to open-loop voltage gain in <i>Electrical</i>
	to voltage output swing in Electrical Characteristics
0	
Changed text to clarify how to adjust input mismatch	nes using null pins in Application Information8
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5 Pin Configuration and Functions

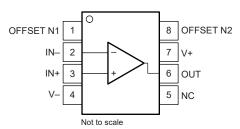


Figure 5-1. D Package, 8-Pin SOIC, P Package, 8-Pin PDIP, and PS Package, 8-Pin SO (Top View)

Table 5-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.	ITPE	DESCRIPTION
IN+	3	Input	Noninverting input
IN-	2	Input	Inverting input
NC	5	_	Do not connect
OFFSET N1	1	Input	External input offset voltage adjustment
OFFSET N2	8	Input	External input offset voltage adjustment
OUT	6	Output	Output
V+	7	_	Positive supply
V-	4	_	Negative supply



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN MA	X UNIT
Vs	Supply voltage ⁽²⁾	Single supply	4	14 V
	Supply Voltage	Dual supply	±ź	v 22
	Innut voltage	put voltage Differential ⁽³⁾ Single-ended ⁽⁴⁾		30 V
	Input voltage			v 22
	Output short-circuit ⁽⁵⁾		Continous	
TJ	Operating junction temperature		-55 15	00 °C
T _{stg}	Storage temperature		– 65 15	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, unless otherwise noted, are with respect to the midpoint between V+ and V-.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
- (5) The output can be shorted to ground or to the negative power supply. Fast ramping shorts to the positive supply can cause permanent damage and eventual destruction.

6.2 ESD Ratings

				VALUE	UNIT
- [V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1000	V	
	V(ESD)	Liectiostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V.	Supply voltage	Single supply	6		36	V
Vs	Supply voltage	Dual supply	±3		±18	V
V _{CM}	Common-mode input voltage	V _S = ±15 V	-13		13	V
T _A	Operating ambient temperature		0		70	°C

6.4 Thermal Information

		OI	OP07x				
	THERMAL METRIC ⁽¹⁾	D (SOIC)	P (PDIP)	UNIT			
		8 PINS	8 PINS				
$R_{\theta JA}$	Junction-to-ambient thermal resistance	127.6	85	°C/W			
R _{0JC(top)}	Junction-to-case (top) thermal resistance	67.1	68.6	°C/W			
$R_{\theta JB}$	Junction-to-board thermal resistance	71.4	556	°C/W			
ΨЈТ	Junction-to-top characterization parameter	18.7	38.3	°C/W			
ΨЈВ	Junction-to-board characterization parameter	70.6	55.2	°C/W			
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	_	_	°C/W			

 For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



6.5 Electrical Characteristics

at $T_A = 25^{\circ}C$, $V_S = \pm 15$ V, $R_L = 2$ k Ω connected to mid-supply, and $V_{CM} = V_{OUT} =$ mid-supply (unless otherwise noted)⁽¹⁾.

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT		
OFFSET VO	LTAGE								
		00070			±60				
,	Input offset voltage	OP07C	T _A = 0°C to 70°C		±85		.,		
V _{os}		00070				±150	μV		
		OP07D	T _A = 0°C to 70°C			±250			
			OP07C		±0.5				
dV _{OS} /dT Input offset voltage drif		T _A = 0°C to 70°C	OP07D			±2.5	μV/°C		
	Long-term drift of input offset voltage ⁽²⁾				±0.4		μV/mo		
	Offset adjustment range	$R_s = 20 \text{ k}\Omega$, see Section 8.1			±4		mV		
	Power supply rejection				7	32	1/0/		
PSRR	ratio	$V_S = \pm 3 \text{ V to } \pm 18 \text{ V}$	T _A = 0°C to 70°C		10	51	μV/V		
INPUT BIAS	CURRENT					-			
					±1.8				
		OP07C	T _A = 0°C to 70°C		±2.2		_		
l _B	Input bias current					±12	nA		
		OP07D	T _A = 0°C to 70°C			±14			
		OP07C			±18				
	Input bias current drift	OP07D				±50	pA/°C		
					±0.8				
		OP07C	T _A = 0°C to 70°C		±1.6		1		
I _{OS} Input o	Input offset current		7			±6	nA		
		OP07D	T _A = 0°C to 70°C			±8			
		OP07C	, , , , , , , , , , , , , , , , , , ,		12				
	Input offset current drift	OP07D				±50	pA/°C		
NOISE									
	Input voltage noise	f = 0.1 Hz to 10 Hz			0.38		μV _{PP}		
	1 0	f = 10 Hz			10.5				
e _N	Input voltage noise density	f = 100 Hz			10.2		nV/√ Hz		
		f = 1 kHz			9.8		- 1107 1112		
	Input current noise	f = 0.1 Hz to 10 Hz			15		pA _{pp}		
	pat sament noise	f = 10 Hz			0.35		Ps 4pp		
i _N	Input current noise density	f = 100 Hz			0.15		pA/√Hz		
'IN	Impat carroin ficios deficity	f = 1 kHz			0.13		p/ (/ 11 12		
INPUT VOLT	│ ſAGE RANGE								
				±13	±14				
V _{CM}	Common-mode voltage	T _A = 0°C to 70°C		±13	±13.5		V		
		OP07C		100	120				
	Common made :-!!	V _{CM} = ±13 V	T _A = 0°C to 70°C	97	120				
CMRR	Common-mode rejection ratio		.A 0 0 10 70 0	94	110		dB		
		OP07D V _{CM} = ±13 V	T _A = 0°C to 70°C	94	106				
INPUT CAPA	ACITANCE		1 A - 0 0 to 10 0	J-T	100				
	Input resistance			7	33		ΜΩ		
rı OPEN-LOOI	<u> </u>						17177		
O1 LIN-LOUI	JAIN	4474.74	OP07C	100	400				
		$1.4 \text{ V} < \text{V}_{\text{O}} < 11.4 \text{ V},$ $R_{\text{L}} = 500 \text{ k}\Omega$	OP07C	100	400				
A _{OL}	Open-loop voltage gain		OFUID	120	400		V/mV		
OL .	-1	V _O = ±10 V	T 40°C to	120	400				
	1	0 =	$T_A = -40^{\circ}C$ to	100	400				



6.5 Electrical Characteristics (continued)

at $T_A = 25^{\circ}C$, $V_S = \pm 15$ V, $R_L = 2$ k Ω connected to mid-supply, and $V_{CM} = V_{OUT} = \text{mid-supply}$ (unless otherwise noted)⁽¹⁾.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
FREQUE	ENCY RESPONSE					
	Unity gain bandwidth		0.4	0.6		MHz
SR	Slew rate	$V_S = 5 \text{ V}, R_L = 2 \text{ k}\Omega$		0.3		V/µs
ОUТРUТ	Γ				•	
			±11.5	±12.8		
	Voltage evitavit evijag	T _A = 0°C to 70°C	±11	±12.6		V
	Voltage output swing	$R_L = 10 \text{ k}\Omega$	±12	±13		V
		$R_L = 1 k\Omega$		±12		
POWER	SUPPLY				•	
n	Dawer dissination	No load		80	150	\/
P_D	Power dissipation	V _S = ±3 V, no load		4	8	mW

⁽¹⁾ The specifications listed in the *Electrical Characteristics* apply to OP07C and OP07D.

6.6 Typical Characteristics

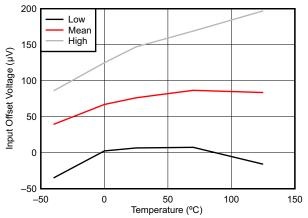


Figure 6-1. Input-Offset Voltage vs Temperature

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⁽²⁾ Because long-term drift cannot be measured on the individual devices before shipment, this specification is not intended to be a warranty. This specification is an engineering estimate of the averaged trend line of drift versus time over extended periods after the first 30 days of operation.



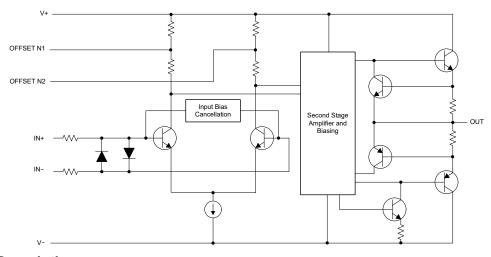
7 Detailed Description

7.1 Overview

These devices offer low offset and long-term stability by means of a low-noise, chopperless, bipolar-input-transistor amplifier circuit. For most applications, external components are not required for offset nulling and frequency compensation. The true differential input, with a wide input-voltage range and outstanding common-mode rejection, provides maximum flexibility and performance in high-noise environments and in noninverting applications. Low bias currents and extremely high input impedances are maintained over the entire temperature range.

These devices are characterized for operation from 0°C to 70°C.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Offset-Voltage Null Capability

The input offset voltage of operational amplifiers (op amps) arises from unavoidable mismatches in the differential input stage of the op-amp circuit caused by mismatched transistor pairs, collector currents, current-gain betas (β), collector or emitter resistors, and so on. The input offset pins allow the designer to adjust for these mismatches by external circuitry. See Section 8 for more details on design techniques.

7.3.2 Slew Rate

The slew rate is the rate at which an operational amplifier can change the output when there is a change on the input. The OP07x have a 0.3-V/µs slew rate.

7.4 Device Functional Modes

The OP07x are powered on when the supply is connected. The devices can be operated as single-supply operational amplifiers or dual-supply amplifiers, depending on the application.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The input offset voltage of operational amplifiers (op amps) arises from unavoidable mismatches in the differential input stage of the op-amp circuit caused by mismatched transistor pairs, collector currents, current-gain betas (β), collector or emitter resistors, and so on. The input offset pins allow the designer to adjust for these mismatches with external circuitry. Figure 8-1 shows how these input mismatches can be adjusted by putting resistors or a potentiometer between the null pins. Use a potentiometer to fine tune the circuit during testing or for applications that require precision offset control. For more information about designing using the input-offset pins, see the *Nulling Input Offset Voltage of Operational Amplifiers* application report.

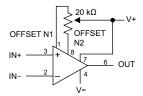


Figure 8-1. Input Offset-Voltage Null Circuit

8.2 Typical Application

The voltage follower configuration of the operational amplifier is used for applications where a weak signal is used to drive a relatively high current load. This circuit is also called a buffer amplifier or unity gain amplifier. The inputs of an operational amplifier have a very high resistance that puts a negligible current load on the voltage source. The output resistance of the operational amplifier is almost negligible, so the amplifier can provide as much current as necessary to the output load.

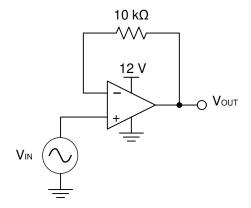


Figure 8-2. Voltage Follower Schematic

8.2.1 Design Requirements

- Output range of 2 V to 11 V
- Input range of 2 V to 11 V

8.2.2 Detailed Design Procedure

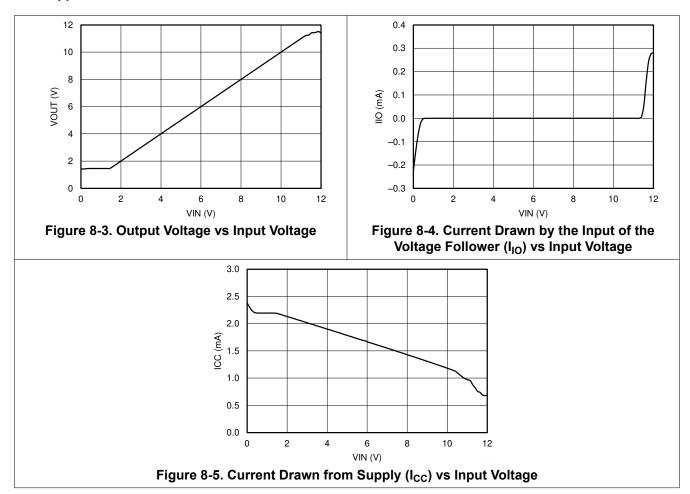
8.2.2.1 Output Voltage Swing

The output voltage of an operational amplifier is limited by the internal circuitry to some level less than the supply rails. For this amplifier, the output voltage swing is within ±12 V, which accommodates the input and output voltage requirements.

8.2.2.2 Supply and Input Voltage

For correct operation of the amplifier, neither input must be higher than the recommended positive supply rail voltage or lower than the recommended negative supply rail voltage. The chosen amplifier must be able to operate at the supply voltage that accommodates the inputs. Because the input for this application goes up to 11 V, the supply voltage must be 12 V. Using a negative voltage on the lower rail, rather than ground, allows the amplifier to maintain linearity for inputs below 2 V.

8.2.3 Application Curves



8.3 Power Supply Recommendations

The OP07x operate from ±3 V to ±18 V supplies; many specifications apply from 0°C to 70°C.

CAUTION

Supply voltages larger than ±22 V can permanently damage the device. See also Section 6.1.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more details on bypass capacitor placement, see *Section 8.4.1*.

8.4 Layout

8.4.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the
 operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low-impedance
 power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. On multilayer PCBs, one or more layers are usually devoted to ground planes.
 A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital
 and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicularly, as opposed to in parallel, with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in *Section 8.4.2*.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

8.4.2 Layout Example

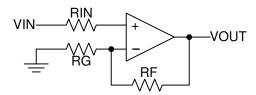


Figure 8-6. Operational Amplifier Schematic for Noninverting Configuration

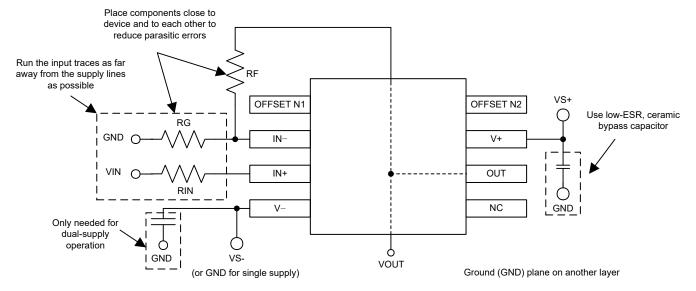


Figure 8-7. Operational Amplifier Board Layout for Noninverting Configuration

9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

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2-Nov-2023

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OP-07DP	LIFEBUY	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	OP-07DP	
OP-07DPS	LIFEBUY	SO	PS	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP-07D	
OP-07DPSR	ACTIVE	SO	PS	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP-07D	Samples
OP-07DPSRG4	ACTIVE	SO	PS	8	2000	TBD	Call TI	Call TI	0 to 70		Samples
OP07-W	ACTIVE	WAFERSALE	YS	0	3603	TBD	Call TI	Call TI			Samples
OP07CD	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	
OP07CDE4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	
OP07CDG4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	
OP07CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	OP07C	Samples
OP07CDRE4	LIFEBUY	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	
OP07CDRG4	LIFEBUY	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	
OP07CP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	OP07CP	Samples
OP07CPE4	ACTIVE	PDIP	Р	8	50	TBD	Call TI	Call TI	0 to 70		Samples
OP07DD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples
OP07DDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples
OP07DDRE4	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	0 to 70		Samples
OP07DP	LIFEBUY	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	OP07DP	
OP07DPE4	LIFEBUY	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	OP07DP	

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

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(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OP-07DPSR	so	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
OP07CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OP07CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OP07CDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OP07DDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OP-07DPSR	SO	PS	8	2000	356.0	356.0	35.0
OP07CDR	SOIC	D	8	2500	340.5	338.1	25.0
OP07CDR	SOIC	D	8	2500	356.0	356.0	35.0
OP07CDRG4	SOIC	D	8	2500	340.5	336.1	25.0
OP07DDR	SOIC	D	8	2500	340.5	338.1	25.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
OP-07DP	Р	PDIP	8	50	506	13.97	11230	4.32
OP-07DPS	PS	SOP	8	80	530	10.5	4000	4.1
OP07CD	D	SOIC	8	75	507	8	3940	4.32
OP07CDE4	D	SOIC	8	75	507	8	3940	4.32
OP07CDG4	D	SOIC	8	75	507	8	3940	4.32
OP07CP	Р	PDIP	8	50	506	13.97	11230	4.32
OP07CP	Р	PDIP	8	50	506	13.97	11230	4.32
OP07DD	D	SOIC	8	75	507	8	3940	4.32
OP07DP	Р	PDIP	8	50	506	13.97	11230	4.32
OP07DPE4	Р	PDIP	8	50	506	13.97	11230	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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